

Final Exam, Solutions

Problem 1 (20 points) Binary Alloy

- a) Find the number of different ways of choosing the n α -sites to be vacated and occupied by β atoms.

$$\#_{\alpha} = \frac{N!}{n!(N-n)!}$$

- b) Find the number of different ways of choosing the n β -sites from which to take the β atoms.

$$\#_{\beta} = \frac{N!}{n!(N-n)!}$$

- c) Find the entropy of the system as a function of n .

$$S(n) = k_B \ln \Omega = k_B \ln(\#_{\alpha} \times \#_{\beta}) = \underline{\underline{2k_B \ln \left(\frac{N!}{n!(N-n)!} \right)}}$$

- d) Find $U(T, N)$.

$$S(n) = 2k_B [N \ln N - n \ln n - (N-n) \ln(N-n) - N + n + (N-n)]$$

$$\frac{1}{T} = \left(\frac{\partial S}{\partial U} \right)_N = \left(\frac{\partial S}{\partial n} \right)_N \underbrace{\left(\frac{\partial n}{\partial U} \right)_N}_{1/\epsilon} = \frac{2k_B}{\epsilon} [-1 - \ln n + 1 + \ln(N-n)]$$

$$\frac{\epsilon}{2k_B T} = -\ln \left(\frac{n}{N-n} \right) \rightarrow \frac{n}{N-n} = e^{-\epsilon/2k_B T}$$

Solving for n gives

$$n = \frac{N}{1 + e^{\epsilon/2k_B T}} \rightarrow \underline{\underline{U(T, N) = \frac{N\epsilon}{1 + e^{\epsilon/2k_B T}}}}$$

Problem 2 (20 points) DNA Model

a) This is a classical system with N non-degenerate states with energies $E_n = n\epsilon$.

$$Z_1 = \sum_{n=0}^N e^{-n\epsilon/k_B T}$$

b) When $k_B T \ll \epsilon$ one need consider only the lowest two energy states; this becomes an energy gap dominated situation.

$$\begin{aligned} \langle n \rangle &= \sum_{n=0}^N n \frac{e^{-n\epsilon/k_B T}}{Z} \\ &\approx \frac{0 e^{-0} + 1 e^{-\epsilon/k_B T}}{e^{-0} + e^{-\epsilon/k_B T}} = \frac{e^{-\epsilon/k_B T}}{1 + e^{-\epsilon/k_B T}} \\ &\approx \underline{e^{-\epsilon/k_B T}} \end{aligned}$$

c) When $k_B T \gg \epsilon$ one can approximate sums over n by integrals. For example

$$Z = \sum_{n=0}^N e^{-n\epsilon/k_B T} = \left(\frac{k_B T}{\epsilon} \right) \sum_{n=0}^N e^{-n\epsilon/k_B T} \left(\frac{\epsilon}{k_B T} \right) \approx \frac{k_B T}{\epsilon} \underbrace{\int_0^\infty e^{-x} dx}_1 = \frac{k_B T}{\epsilon}$$

d) In a similar manner

$$\begin{aligned} \langle n \rangle &= \sum_{n=0}^N n \frac{e^{-n\epsilon/k_B T}}{Z} \\ &= \sum_{n=0}^N \frac{n\epsilon}{k_B T} e^{-n\epsilon/k_B T} = \left(\frac{k_B T}{\epsilon} \right) \sum_{n=0}^N \frac{n\epsilon}{k_B T} e^{-n\epsilon/k_B T} \left(\frac{\epsilon}{k_B T} \right) \\ &\approx \frac{k_B T}{\epsilon} \underbrace{\int_0^\infty x e^x dx}_1 \\ &\approx \underline{\frac{k_B T}{\epsilon}} \end{aligned}$$

Alternatively use $Z_1 = 1/(\beta\epsilon)$.

$$\langle n \rangle = \frac{\langle U \rangle}{\epsilon} = \frac{1}{\epsilon} \left(\frac{-1}{Z} \frac{\partial Z}{\partial \beta} \right) = \frac{1}{\epsilon} \left(\frac{-1}{Z} \right) \left(\frac{-Z}{\beta} \right) = \underline{\frac{k_B T}{\epsilon}}$$

Problem 3 (20 points) Spin Waves

a)

$$D(\vec{k}) = \frac{L_x L_y L_z}{2\pi 2\pi 2\pi} = \frac{V}{(2\pi)^3}$$

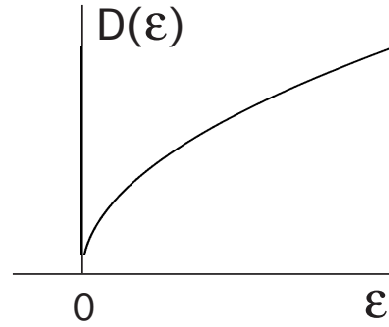
b)

$$\#(\omega) = (\text{volume of sphere in } k\text{-space}) \times D(\vec{k})$$

$$= \frac{4}{3}\pi k^3(\omega) \frac{V}{(2\pi)^3} \quad \text{use } k = (\omega/a)^{1/2}$$

$$= \frac{V}{6\pi^2} \left(\frac{\omega}{a}\right)^{3/2}$$

$$D(\omega) = \frac{d\#(\omega)}{d\omega} = \frac{V}{(2\pi)^2} a^{-3/2} \omega^{1/2}$$



c)

$$U = \int_0^\infty \langle \epsilon(\omega) \rangle D(\omega) d\omega$$

$$= \frac{V}{(2\pi)^2} a^{-3/2} \int_0^\infty \frac{\hbar\omega}{(e^{\hbar\omega/k_B T} - 1)} \omega^{1/2} d\omega + \text{Z.P. contribution}$$

$$= \frac{V}{(2\pi)^2} \left(\frac{1}{\hbar a}\right)^{3/2} (k_B T)^{5/2} \underbrace{\int_0^\infty \frac{x^{3/2}}{e^x - 1} dx}_{\equiv I} + \text{Z.P. contribution}$$

$$C_V(T, V) = \left(\frac{\partial U}{\partial T}\right)_V = \frac{5}{8\pi^2} k_B V \left(\frac{k_B T}{\hbar a}\right)^{3/2} I$$

d) There is no energy gap behavior ($C_V \propto T^n e^{-\Delta/k_B T}$) because of the integration over a continuous distribution of gaps ($\Delta = \hbar\omega$), some of which are less than $k_B T$ for any physical T .

Problem 4 (20 points) Graphene

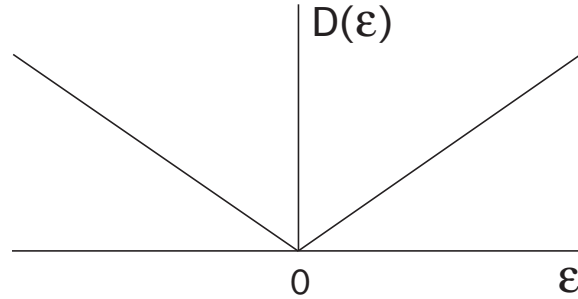
a)

$$D(\vec{k}) = \frac{L_x L_y}{2\pi 2\pi} = \frac{A}{(2\pi)^2}$$

b)

$$\begin{aligned} \#(\epsilon) &= 2 \times (\text{area of disk in k-space}) \times D(\vec{k}) \\ &= 2 \times \pi k^2(\epsilon) \frac{A}{(2\pi)^2} \quad \text{use } k = \frac{\epsilon}{\hbar v} \\ &= \frac{A}{2\pi} \left(\frac{1}{\hbar v} \right)^2 \epsilon^2 \\ D_c(\epsilon) &= \frac{d\#(\epsilon)}{d\epsilon} = \frac{A}{\pi} \left(\frac{1}{\hbar v} \right)^2 \epsilon \end{aligned}$$

c)



d)

$\mu(T = 0)$ rests at the last filled state at $T = 0$ which is at the top of the valence band, so $\mu(T = 0) = 0$.

$D(\epsilon)$ is symmetric about $\epsilon = 0$. If μ stays at $\epsilon = 0$ the symmetry of $\langle n(\epsilon, T) \rangle$ assures that as T increases the number of electrons lost from the valence band is exactly equal to the number of electrons appearing in the conduction band. Thus $\mu(T) = 0$ for all T covered by this model.

e)

$$\begin{aligned} U &= \int_{-\infty}^{\infty} \epsilon \langle n(\epsilon, T) \rangle D(\epsilon) d\epsilon \\ &= 2 \int_0^{\infty} \epsilon \langle n(\epsilon, T) \rangle D_c(\epsilon) d\epsilon \\ &= \frac{A}{\pi} \left(\frac{1}{\hbar v} \right)^2 \int_0^{\infty} \frac{1}{(e^{\epsilon/k_B T} + 1)} \epsilon^2 d\epsilon \\ &= \frac{A}{\pi} \left(\frac{1}{\hbar v} \right)^2 (k_B T)^3 \underbrace{\int_0^{\infty} \frac{x^2}{(e^x + 1)} dx}_{\equiv I} \\ &= \underline{\underline{\frac{A}{\pi} \left(\frac{1}{\hbar v} \right)^2 (k_B T)^3 I}} \end{aligned}$$

f)

$C_A(T) = (\partial U / \partial T)_A$ so $C_A(T)$ will be proportional to T^2 , that is the temperature exponent $n = 2$.

Problem 5 (20 points) BEC

a)

$$\begin{aligned}
 N &= \int_0^\infty \langle n \rangle D(\epsilon) d\epsilon \\
 &= \int_0^\infty \frac{1}{e^{(\epsilon-\mu)/k_B T} - 1} \left[\frac{V}{(2\pi)^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} \sqrt{\epsilon} \right] d\epsilon \\
 &= \frac{V}{4\pi^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} \int_0^\infty \frac{\sqrt{\epsilon}}{e^{(\epsilon-\mu)/k_B T} - 1} d\epsilon \\
 &= \frac{V}{4\pi^2} \left(\frac{2mk_B T}{\hbar^2} \right)^{3/2} \underbrace{\int_0^\infty \frac{\sqrt{x}}{e^{(x-y)} - 1} dx}_{\equiv I(y)} \\
 n &= \frac{V}{4\pi^2} \left(\frac{2mk_B T}{\hbar^2} \right)^{3/2} I(y)
 \end{aligned}$$

b) Bose-Einstein condensation begins when the above condition is satisfied with $\mu = 0$ which also means our dimensionless parameter $y = 0$.

$$n_c = \frac{V}{4\pi^2} \left(\frac{2mk_B T_c}{\hbar^2} \right)^{3/2} I(y = 0)$$

c)

$dU = TdS - PdV + \mu dN$; change independent variables to T, V, N :

$$dS = \left. \frac{\partial S}{\partial T} \right|_{T,V} dT + \left. \frac{\partial S}{\partial V} \right|_{T,N} dV + \left. \frac{\partial S}{\partial N} \right|_{T,V} dN$$

So $\partial U / \partial N|_{V,T} = \mu + T \partial S / \partial N|_{T,V}$.

Now use Maxwell relation derivable from $dF = \dots$ on the information sheet: $\partial S / \partial N|_{T,V} = -\partial \mu / \partial T|_{T,N}$. so

$$\left. \frac{\partial U}{\partial N} \right|_{V,T} = \mu - T \left. \frac{\partial \mu}{\partial T} \right|_{N,V} = -T^2 \left. \frac{\partial}{\partial T} \frac{\mu}{T} \right|_{N,V} = \left. \frac{\partial(\beta\mu)}{\partial \beta} \right|_{N,V}$$

In the Bose condensed phase $\mu = 0$ and is independent of the temperature, so both terms in $\partial U / \partial N$ are zero.

d)

From answer to part a)

$$n = \frac{1}{4\pi^2} \left(\frac{2mk}{\hbar^2} \right)^{3/2} T^{3/2} \int_0^\infty \frac{\sqrt{x} dx}{e^{(x-y)} - 1} \quad C \times \frac{N}{V} \beta^{3/2} = \int_0^\infty \frac{\sqrt{x} dx}{e^{(x-y)} - 1}$$

where C is a collection of constants.

Differentiate this equation implicitly w.r.t. β and $y = \mu\beta$,

$$\frac{3}{2} \times \frac{N}{V} \beta^{1/2} = \left(\int_0^\infty \sqrt{x} dx \frac{e^{(x-y)}}{(e^{(x-y)} - 1)^2} \right) \frac{dy}{d\beta}$$

Both the term on the left and the term in () are positive definite. Thus $dy/d\beta > 0$.

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8.044 Statistical Physics I
Spring 2013

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